Docket No.: 071971-0432 <u>PATENT</u>

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of : Customer Number: 53080

Satoshi SHIBATA : Confirmation Number: 2300

Patent No.: 7,737,012

Application No.: 10/557,746 : Group Art Unit: 2813

: Allowed: February 05, 2010 Filed: November 21, 2005 : Examiner: Latanya N. CRAWFORD

For: MANUFACTURING METHOD OF A SEMICONDUCTOR DEVICE

#### REQUEST FOR CERTIFICATE OF CORRECTION UNDER 37 CFR 1.322

Mail Stop Certificate of Correction Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In reviewing the above-identified patent, a printing error was discovered therein requiring correction in order to conform the Official Record in the application.

The error noted is set forth on the attached copy of form PTO-1050 Rev. 2-93 in the manner required by the Commissioner's Notice.

Specifically, the section entitled --OTHER PUBLICATIONS-- and the literature reference -BORLAND "Low Temperature Activation of Ion Implanted Dopants: A Review", Japan Society of Applied Physics, 202, pp. 85-88-- has been erroneously omitted from the patent. Attached, please find our Information Disclosure Statement and PTO Form 1449 filed November 21, 2005, as well as the copy of the 1449 initialed by the Examiner which lists the omitted reference.

10/557,746

The change requested herein occurred as a result of printing the Letters Patent and the

Certificate should be issued without expense under Rule 322 of the Rules of Practice.

Accordingly, Applicants request issuance of the Certificate of Correction.

Please charge any shortage in fees due in connection with the filing of this paper to Deposit

Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

MODERMOTT WILL & EMERY LLP

Michael E. Fogarty Registration No. 36,139

600 13<sup>th</sup> Street, N.W. Washington, DC 20005-3096 Phone: 202.756.8000 MEF:sls

Facsimile: 202.756.8087

Date: September 8, 2010

Date: September 8, 2010

WDC99 1915874-1.071971.0432

Please recognize our Customer No. 53080 as our correspondence address.

#### UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : 7.737.012 Page 1 of 1

APPLICATION NO. : 10/557.746

ISSUE DATE

: June 15, 2010

INVENTOR(S)

: Satoshi Shibata

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

#### ON THE TITLE PAGE:

In Item "(56) References Cited", under "OTHER PUBLICATIONS" and before the Examiner Information, insert the following:

> - BORLAND "Low Temperature Activation of Ion Implanted Dopants: A Review", Japan Society of Applied Physics, 202, pp. 85-88 --

MAILING ADDRESS OF SENDER (Please do not use customer number below):

600 13th Street, N.W.

Washington, D. C. 20005-3096

This collection of information is required by 37 CFR 1,322, 1,323, and 1,324. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14 This collection is estimated to take 1.0 hour to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: ATTENTION Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

### JAP15 Rec'd PCT/PTO 2.1 NOV 2005

Docket No.: 071971-0432 <u>PATENT</u>

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of : Customer Number: 20277

Satoshi SHIBATA : Confirmation Number: Not yet

assigned

Application No.: Not yet assigned : Group Art Unit: Not yet assigned

Filed: November 21, 2005 : Examiner: Not yet assigned

For: MANUFACTURING METHOD OF A SEMICONDUCTOR DEVICE

#### INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner for Patents and Trademarks Washington, D. C. 20231

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached form PTO-1449. It is respectfully requested that the references be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed with the application and no certification or fee is required.

A copy of the foreign search report is attached for the Examiner's information.

Please note this is a PCT application in the entry of the National Phase in the U.S. and copies of the references cited were transmitted by WIPO and are believed to be in the file of the above identified application and readily available to the Examiner. Therefore it is believed that Applicants have met all requirements regarding duty of disclosure under 37

#### Not yet assigned

## IAP15 Rec'd PCT/PTO 21 NOV 2005

CFR 1.56. Acknowledgement and consideration of these documents are respectfully requested.

A copy of the foreign search report is attached for the Examiner's information. Please note this is a PCT application in the entry of the National Phase in the U.S. Since the Search Report was from the U.S. JPO or EPO search authorities, copies of these references should have been supplied to the USPTO under the trilateral agreement and are believed to be in the file of the above identified application and readily available to the Examiner.

Respectfully submitted,

McDERMOTZ WILL & EMERY LLP

Michael E. Fogarty
Registration No. 36;13

600 13<sup>th</sup> Street, N.W. Washington, DC 20005-3096 Phone: 202.756.8000 MEF:aph Facsimile: 202.756.8087 **Date: November 21, 2005**  Please recognize our Customer No. 20277 as our correspondence address.

# IAP15 Rec'd PCT/PTO 21 NOV 2005

SHEET 1 OF 1

INFORMATION DISCLOSURE CITATION IN AN APPLICATION					ATTY. DOCKET NO. 071971-0432  APPLICANT		SERIAL NO. Not yet assigned 10/557746			
					Satoshi SHIBA	Satoshi SHIBATA				
(PTO-1449)					November 21, 2				assigned	
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		US 6,074,937		6-13-2000	Pramanick, et	al.				
		US 5,602,045		2-11-1997	Kimura					
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			JP 04-058524	2-25-1992	Fujitsu Ltd.					
			JP 06-089869	3-29-1994	Oki Electric Industry Co., Ltd.			1.		
			JP 05-190850	7-30-1993	Sony Corp					
			JP 08-203842	8-9-1996	Sony Corp					
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INITIALS	INITIALS  CITE (NO. District series), symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.  BORLAND 'Low Temperature Activation of ton Implanted Dopants: A Review', Japan Society of Applied Physics, 2002, pp. 85-88									
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EXAMINER						DATE CONSIDERED				

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## IAP15 Rec'd PCT/PTO 21 NOV 2005

SHEET 1 OF 1 INFORMATION DISCLOSURE ATTY DOCKET NO SERIAL NO 071971-0432 Not yet assigned CITATION IN AN 10/557746 APPLICATION APPLICANT Satoshi SHIBATA FILING DATE GROUP (PTO-1449) November 21, 2005 Not yet assigned U.S. PATENT DOCUMENTS EXAMINER'S Document Number Name of Patentee or Applicant of Cited Pages, Columns, Lines, Where INITIALS NO. Number-Kind Codes of trees MM-DD-YYYY Relevant Passages or Relevant Figures Appear 6.074.937 US 6-13-2000 Pramanick, et al. /I C/ US 5.602.045 2-11-1997 Kimura /LC/ US US US US US ÜS US US US US US US FOREIGN PATENT DOCUMENTS EXAMINER'S Pages, Columns, Lines Where Relevant Foreign Patent Document Publication Date Name of Paten INITIALS Country Codes -Number 4 -Kind Codes (if known) MM-DD-YYYY Applicant of Cited Docume CITE Figures Appear NO JP 04-058524 2-25-1992 Fujitsu Ltd. /LC/ JP 06-089869 3-29-1994 Oki Electric Industry Co.. /LC/ Ltd. /LC/ JP 05-190850 7-30-1993 Sony Corp JP 08-203842 8.9.1996 Sony Corp OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.) Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, fournal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where INITIALS CITE nublished BORLAND "Low Temperature Activation of Ion Implanted Dopants: A Review", Japan Society of Applied /L.C./ Physics, 2002, pp. 85-88 FYAMINER DATE CONSIDERED 06/04/2007 /Latanya Crawford/

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered include copy of this form with next communication to applicant.

<sup>1</sup> Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.